

## CLAIMS

What is claimed is:

1. A reconfigurable organic light-emitting device, comprising:
  - at least two organic light-emitting layers; and
  - 5 at least one high-energy-gap carrier-blocking layer, formed between each of the organic light-emitting layers; wherein the organic light-emitting layers and the high-energy gap carrier-blocking layer can be heated to induce the inter-diffusion process, so as to change the structure of the reconfigurable organic light-emitting device to emit light of different spectra.
- 10 2. The organic light-emitting device as recited in claim 1, further comprising an upper electrode and a lower electrode sandwiching the organic light-emitting layers and the high-energy-gap carrier-blocking layer. By applying a bias voltage thereon, the reconfigurable organic light-emitting device may emit lights.
3. The organic light-emitting device as recited in claim 2, further comprising a light-to-heat  
15 conversion layer, wherein by shining a light-beam thereon, the reconfigurable organic light-emitting device may be heated.
4. The organic light-emitting device as recited in claim 2, further comprising a built-in resistive heating electrode, wherein by applying a current thereon, the reconfigurable organic light-emitting device may be heated.
- 20 5. The organic light-emitting device as recited in claim 2, further comprising an external heating source.
6. The organic light-emitting device as recited in claim 5, wherein the external heating source is a patterned resistive heating electrode, wherein by applying a current thereon, the reconfigurable organic light-emitting device may be heated.
- 25 7. The organic light-emitting device as recited in claim 4, wherein the built-in resistive heating electrode is a patterned resistive conductor.

8. The organic light-emitting device as recited in claim 3, wherein the light-beam is a laser beam.
9. The organic light-emitting device as recited in claim 1, wherein each of the high-energy - gap carrier-blocking layer has a different glass transition temperature, and the glass transition temperatures of the high-energy-gap carrier-blocking layer are smaller than the glass transition temperatures of the organic light-emitting layers.  
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10. The organic light-emitting device as recited in claim 1, wherein the emission spectrum of the reconfigurable organic light-emitting device is one of the characteristic spectra of the at least two organic light-emitting layers, and when the structure of the reconfigurable organic light-emitting device is changed, the emission spectrum of the reconfigurable organic light-emitting device changes from the characteristic spectrum of one layer of the at least two organic light-emitting layers to that of another layer of the at least two organic light-emitting layers.  
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11. A display apparatus employing the organic light-emitting device, comprising:  
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    a lower electrode;  
    a layers of the reconfigurable light-emitting device formed on the lower electrode;  
    and  
    an upper electrode formed on the layer of the reconfigurable light-emitting device; the structure of the reconfigurable organic light-emitting layer being locally reconfigured via a patterned heating source, and by applying a bias voltage between the upper electrode and the lower electrode, light of different spectra being emitted.  
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12. The display apparatus as recited in claim 11, wherein the layers of the reconfigurable organic light-emitting device further comprises:  
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    at least two organic light-emitting layers; and  
    at least one high-energy-gap carrier-blocking layer, formed between each of the organic light-emitting layers.

13. The display apparatus as recited in claim 12, wherein each of the high-energy-gap carrier-blocking layer has a different glass transition temperature, and the glass transition temperatures of the high-energy-gap carrier-blocking layers are smaller than the glass transition temperatures of the organic light-emitting layers.
- 5    14. The display apparatus as recited in claim 12, wherein the emission spectrum of the reconfigurable organic light-emitting device is one of the characteristic spectra of the at least two organic light-emitting layers, and the emission spectrum of reconfigurable organic light-emitting is changed from the characteristic spectrum of one layer of the at least two organic light-emitting layers to another layer of the at least two organic light-emitting layers when the reconfigurable organic light-emitting device changes its structure.
- 10    15. The display apparatus as recited in claim 11, further comprising a light-to-heat conversion layer, wherein by shining a light-beam thereon, the reconfigurable organic light-emitting device may be heated.
- 15    16. The display apparatus as recited in claim 11, further comprising an external heating source, by which the reconfigurable organic light-emitting device may be heated.
17. The display apparatus as recited in claim 11, further comprising a built-in resistive heating electrode, wherein by applying a current thereon, the reconfigurable organic light-emitting device may be heated.
- 20    18. The display apparatus as recited in claim 17, wherein the lower electrode may be used on the built-in resistive heating electrode
19. The display apparatus as recited in claim 11, wherein the bias voltage applied between the upper electrode and the lower electrode is within the range of 2 volts to 15 volts.
20. A display apparatus employing the organic light-emitting device, comprising:
- 25              a substrate;
- a lower electrode formed on the substrate;

- an insulating layer formed on the lower electrode;
  - an upper electrode separating island formed on the insulating layer;
  - a layer of reconfigurable organic light-emitting device formed on the lower electrode, the insulating layer, and the upper electrode separating island; and
- 5        an upper electrode formed on the layer of the reconfigurable organic light-emitting device; wherein the structure of the layer of the reconfigurable organic light-emitting device can be reconfigured via a patterned heating source, and by applying a bias voltage between the upper electrode and the lower electrode, light of different spectra can be emitted.
- 10      21. The display apparatus as recited in claim 20, wherein the layer of the reconfigurable organic light-emitting device further comprises:
- at least two organic light-emitting layers; and
  - at least one high-energy gap carrier-blocking layer, formed between each of the organic light-emitting layers.
- 15      22. The display apparatus as recited in claim 21, wherein each of the high-energy-gap carrier-blocking layer has a different glass transition temperature, and the glass transition temperatures of the high-energy-gap carrier-blocking layers are smaller than the glass transition temperatures of the organic light-emitting layers.
- 20      23. The display apparatus as recited in claim 21, wherein the emission spectrum of the reconfigurable organic light-emitting device is one of the characteristic spectra of the at least two organic light-emitting layers, and the emission spectrum of reconfigurable organic light-emitting is changed from the characteristic spectrum of one layer of the at least two organic light-emitting layers to that of another layer of the at least two organic light-emitting layers when the reconfigurable organic light-emitting device changes its structure.
- 25      24. The display apparatus as recited in claim 20, further comprising a light-to-heat

- conversion layer, wherein by shining a light-beam thereon, the reconfigurable organic light-emitting device may be heated.
25. The display apparatus as recited in claim 24, wherein the light-beam is a laser beam.
26. The display apparatus as recited in claim 24, wherein the light-to-heat conversion layer is  
5 any one of the upper electrode and the lower electrode.
27. The display apparatus as recited in claim 24, wherein the light-to-heat conversion layer is formed outside of the upper electrode and the lower electrode.
28. The display apparatus as recited in claim 24, wherein the light-to-heat conversion layer is formed between the upper electrode and the lower electrode.
- 10 29. The display apparatus as recited in claim 20, further comprising a built-in resistive heating electrode, wherein by applying a current thereon, the reconfigurable organic light-emitting device may be heated.
30. The display apparatus as recited in claim 29, wherein the built-in resistive heating electrode is a layer of patterned resistive conductor.
- 15 31. The display apparatus as recited in claim 30, wherein the layer of patterned resistive conductor is any one of the upper electrode and the lower electrode.
32. The display apparatus as recited in claim 30, wherein the layer of patterned resistive conductor is formed outside of the upper electrode and the lower electrode.
33. The display apparatus as recited in claim 24, further comprising an external heating  
20 source.
34. The display apparatus of claim 33, wherein the external heating source is a layer of patterned resistive conductor, wherein by applying a current thereon, the reconfigurable organic light-emitting device may be heated.
35. The display apparatus as recited in claim 20, wherein the upper electrode and the lower  
25 electrode by vertically cross each other.
36. A display apparatus employing the organic light-emitting device, comprising:

- a substrate;
- a lower electrode formed on the substrate;
- an insulating layer formed on the lower electrode;
- 5 a layer of reconfigurable organic light-emitting device formed on the lower electrode and the insulating layer;
- an upper electrode formed on the layer of the reconfigurable organic light-emitting device; and
- 10 a transistor circuit electrically connected with the upper electrode and the lower electrode; wherein the structure of the layer of the reconfigurable organic light-emitting device is reconfigured via a patterned heating source, and by applying a bias voltage between the upper electrode and the lower electrode, controlled by the transistor circuit, light of different spectra is emitted.
37. The display apparatus as recited in claim 36, wherein the layer of the reconfigurable organic light-emitting device further comprising:
- 15 at least two organic light-emitting layers; and
- at least one high-energy-gap carrier-blocking layer, formed between each of the organic light-emitting layer.
38. The display apparatus as recited in claim 37, wherein each of the high-energy-gap carrier-blocking layer has a different glass transition temperature, and the glass transition temperatures of the high-energy-gap carrier-blocking layers are smaller than the glass transition temperatures of the organic light-emitting layers.
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39. The display apparatus as recited in claim 37, wherein the emission spectrum of the reconfigurable organic light-emitting device is one of the characteristic spectra of the at least two organic light-emitting layers, and the emission spectrum of reconfigurable organic light-emitting is changed from the characteristic spectrum of one layer of the at least two organic light-emitting layers to that of another layer of the at least two organic
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light-emitting layers when the reconfigurable organic light-emitting device changes its structure.

40. The display apparatus as recited in claim 37, further comprising a light-to-heat conversion layer, wherein by shining a light-beam thereon, the reconfigurable organic light-emitting device may be heated.  
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41. The display apparatus as recited in claim 40, wherein the light-beam is a laser beam.
42. The display apparatus as recited in claim 40, wherein the light-to-heat conversion layer is any one of the upper electrode and the lower electrode.
43. The display apparatus as recited in claim 40, wherein the light-to-heat conversion layer is  
10 formed outside of the upper electrode and the lower electrode.
44. The display apparatus as recited in claim 40, wherein the light-to-heat conversion layer is formed between the upper electrode and the lower electrode.
45. The display apparatus as recited in claim 37, further comprising a built-in resistive heating electrode, wherein by applying a current thereon, the reconfigurable organic  
15 light-emitting device may be heated.
46. The display apparatus as recited in claim 37, wherein the built-in resistive heating electrode is a layer of patterned resistive conductor.
47. The display apparatus as recited in claim 46, wherein the layer of patterned resistive conductor is outside of the lower electrode.
- 20 48. The display apparatus as recited in claim 37, further comprising an external heating source.
49. The display apparatus of claim 48, wherein the external heating source is a layer of patterned resistive conductor, wherein by applying a current thereon, the reconfigurable organic light-emitting device may be heated.